

Specification Amendments

Please replace the paragraph beginning at page 3 line 1 with the following amended paragraph:

U.S. Patent No. 5,153,701 5,153,761 discloses a prior art image transistor. A cross-sectional view of which is a similar device is shown in FIG. 3. This image transistor 100 generally comprises a liquid crystal modulator 102, a photoconductor 104, including a charge separation layer 106 and a charge generation layer 108, with a mirror 110 and light block layer 112 disposed between the photoconductor and the modulator. Transparent electrodes 114a and 114b are disposed on opposing sides of the modulator 102, and these are connected to an electrical power source 116 for producing an electrical field that passes through the modulator and the photoconductor. The entire structure is disposed between a front glass 118 and rear glass 120.